

SULIT



UNIVERSITI TUN HUSSEIN ONN MALAYSIA

PEPERIKSAAN AKHIR SEMESTER III SESI 2012/2013

NAMA KURSUS	:	ELECTRICAL TECHNOLOGY AND MICRO PROCESSING
KOD KURSUS	:	DAJ 32302
PROGRAM	:	DAJ
TARIKH PEPERIKSAAN	:	MEI 2013
JANGKA MASA	:	2 JAM
ARAHAN	:	JAWAB LIMA (4) SOALAN DARIPADA ENAM (6) SOALAN

KERTAS SOALANINI MENGANDUNGI TUJUH (7) MUKA SURAT BER CETAK

SULIT

SOALAN DI DALAM BAHASA MELAYU

Q1 (a) Berikan perbezaan di antara semikonduktor jenis-P dan jenis-N, termasuk gambaran struktur atom.

(10 markah)

(b) Lukis dan terangkan rekifikasi gelombang penuh menggunakan kapasitor pelicinkan dengan beban rintangan dan mencari satu ungkapan untuk faktor riak merentasi beban.

(10 markah)

Q2 (a) Andaikan diod adalah diod-kuasa rendah dengan nilai rintangan hadapan 6 ohm seperti yang ditunjukkan dalam **Rajah S1**. Potensi voltan halangan masih: $V_\phi = 0.45 \text{ volt}$ (khas untuk diod germanium) Tentukan nilai I_D jika $V_A = 6 \text{ volt}$.

(15 markah)

(b) Senaraikan tiga jenis diod dan kegunaannya dalam litar elektronik.

(5 markah)

Q3 (a) Lukis rekabentuk untuk pemandu motor dc menggunakan empat transistor NPN. Jelaskan aliran arus pemandu dan arah motor.

(20 markah)

Q4 (a) Terangkan perbezaan besar antara mikropemproses dan mikropengawal, termasuk ciri-ciri tipikal mikropengawal.

(15 markah)

(b) Terangkan faedah utama dan had menggunakan mikropengawal.

(5 markah)

Q5 (a) Jelaskan organisasi asas memori data PIC.

(10 markah)

(b) Jelaskan organisasi asas timbunan PIC.

(10 markah)

Q6 (a) Merujuk kepada litar dalam **Rajah Q2**, apakah tujuan litar RC yang disambungkan ke input RESET mikropengawal.

(5 markah)

(b) Apakah kesan melaksanakan arahan berikut

**movlw b'11110000'
movwf trisb**

(10 markah)

(c) Menganggap bahawa kod berikut baru sahaja dilaksanakan. Apa kandungan biner daftar kerja.

**movlw 2f
addlw 55**

(5 markah)

SOALAN DI DALAM BAHASA INGGERIS

Q1 (a) Give the differences between P-type and N-type semiconductors. Include atomic structure illustration.

(10 marks)

(b) Draw and explain full wave rectifier using a smoothing capacitor with a resistance load and find an expression for ripple factor across load.

(10 marks)

Q2 (a) Assume the diode is a low-power diode with a forward resistance value of 6 ohms as shown in **FIGURE Q1**. The barrier potential voltage is still: $V_\phi = 0.45$ volts (typical for a germanium diode) Determine the value of I_D if $V_A = 6$ volts.

(15 marks)

(b) List down the three types of diodes and their uses in electronic circuit.

(5 marks)

Q3 (a) Draw the design for dc driver motor using four NPN transistors. Describe the driver current flow and motor direction.

(20 marks)

Q4 (a) Explain the major differences between a microprocessor and a microcontroller, including the typical features of a microcontroller.

(15 marks)

(b) Explain the major benefits and limitations of using a microcontroller.

(5 marks)

- Q5** (a) Explain the basic organization of the PIC data memory.
(10 marks)
- (b) Explain the basic organization of the PIC stack.
(10 marks)
- Q6** (a) For the following circuit in **FIGURE Q2**, what is the purpose of RC circuit that is connected to the RESET input of the microcontroller.
(5 marks)
- (b) What is the effect of executing the following instructions?
- movlw b'11110000'**
movwf trisb
- (10 marks)
- (c) Assume that the following code has just been executed. What the binary content of the working register.
movlw 2f
addlw 55
- (5 marks)

- END OF QUESTION -

**PEPERIKSAAAN AKHIR
FINAL EXAMINATION**

SEMESTER / SESI : SEM III / 2012/2013

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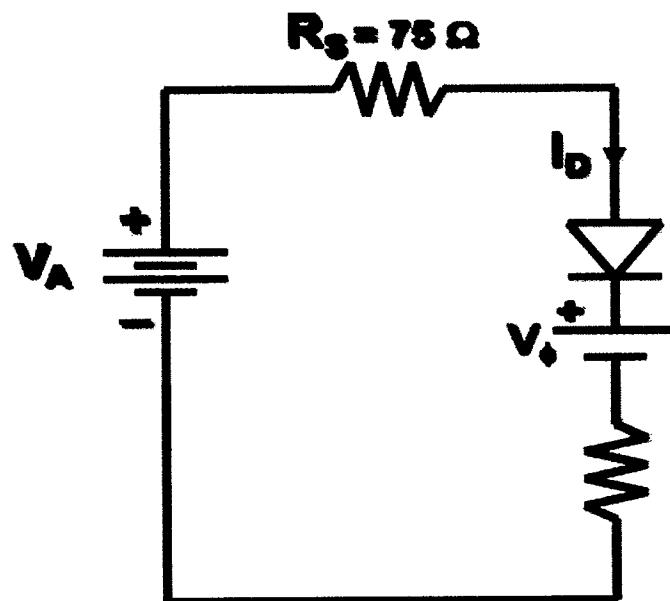
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RAJAH S1 / FIGURE Q1

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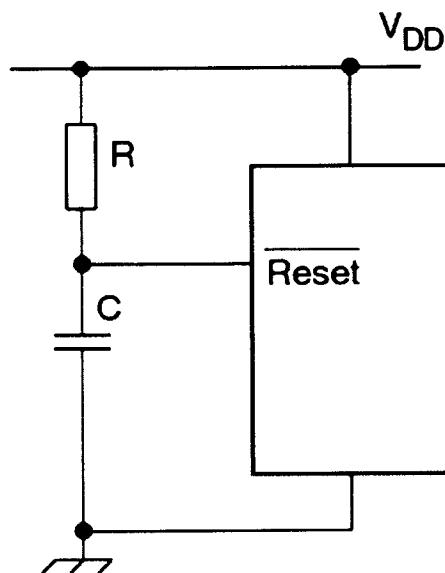
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RAJAH S2 / FIGURE Q2